



Integrated Device Technology, Inc.

FAST CMOS 16-BIT BUFFER/LINE DRIVER

IDT54/74FCT16240T/AT/CT/ET
IDT54/74FCT162240T/AT/CT/ET

FEATURES:

• Common features:

- 0.5 MICRON CMOS Technology
- **High-speed, low-power CMOS replacement for ABT functions**
- **Typical tsk(o) (Output Skew) < 250ps**
- **Low input and output leakage $\leq 1\mu\text{A}$ (max)**
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- 25 mil pitch SSOP and Cerpack Packages and 19.6 mil pitch TSSOP Package
- Extended commercial range of -40°C to $+85^{\circ}\text{C}$
- $V_{CC} = 5\text{V} \pm 10\%$

• Features for FCT16240T/AT/CT/ET:

- High drive outputs (-32mA IOH, 64mA IOL)
- Power off disable outputs permit "live insertion"
- Typical VOLP (Output Ground Bounce) < 1.0V at $V_{CC} = 5\text{V}$, $T_A = 25^{\circ}\text{C}$

• Features for FCT162240T/AT/CT/ET:

- Balanced Output Drivers: $\pm 24\text{mA}$ (commercial), $\pm 16\text{mA}$ (military)
- Reduced system switching noise
- Typical VOLP (Output Ground Bounce) < 0.6V at $V_{CC} = 5\text{V}$, $T_A = 25^{\circ}\text{C}$

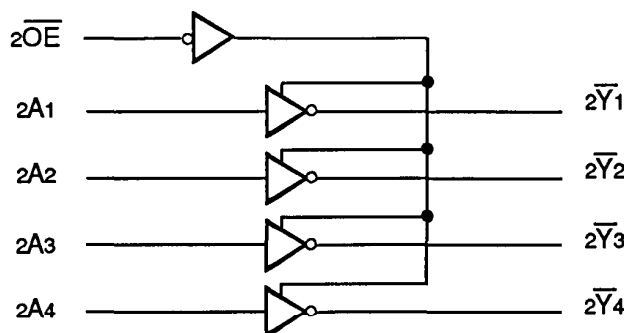
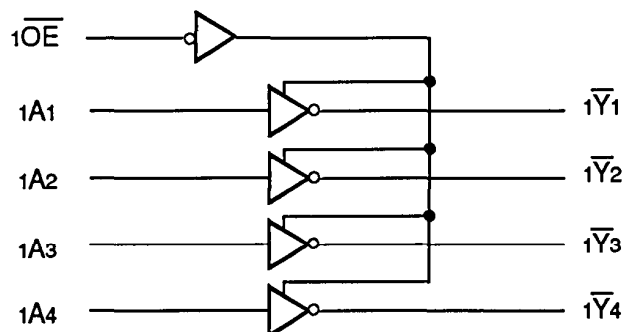
DESCRIPTION:

The IDT54/74FCT16240T/AT/CT/ET and IDT54/74FCT162240T/AT/CT/ET 16-bit buffer/line drivers are built using advanced dual metal CMOS technology. These high-speed, low-power devices offer bus/backplane interface capability with improved packing density. The flow-through organization of signal pins simplifies layout. The three-state controls are designed to operate these devices in a Quad-Nibble, Dual-Byte or single 16-bit word mode. All inputs are designed with hysteresis for improved noise margin.

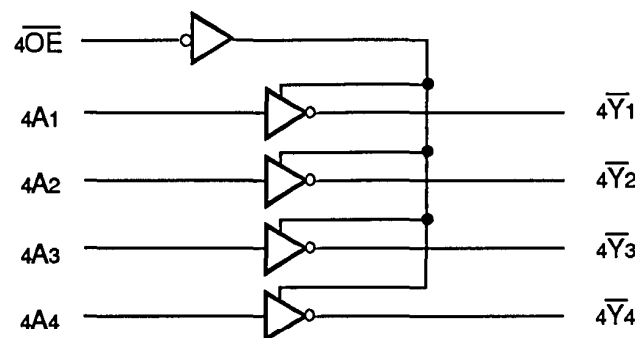
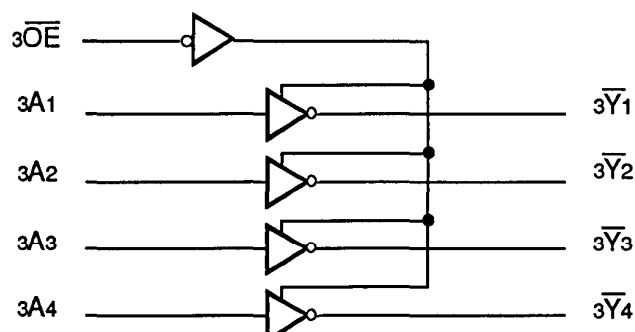
The IDT54/74FCT16240T/AT/CT/ET are ideally suited for driving high capacitance loads and low-impedance backplanes. The output buffers are designed with power off disable capability to allow "live insertion" of boards when used as backplane drivers.

The IDT54/74FCT162240T/AT/CT/ET have balanced output drive with current limiting resistors. This offers low ground bounce, minimal undershoot, and controlled output fall times—reducing the need for external series terminating resistors. The IDT54/74FCT162240T/AT/CT/ET are plug-in replacements for IDT54/74FCT16240T/AT/CT/ET and 54/74ABT16240 for on-board interface applications.

FUNCTIONAL BLOCK DIAGRAM



2541 drw 01



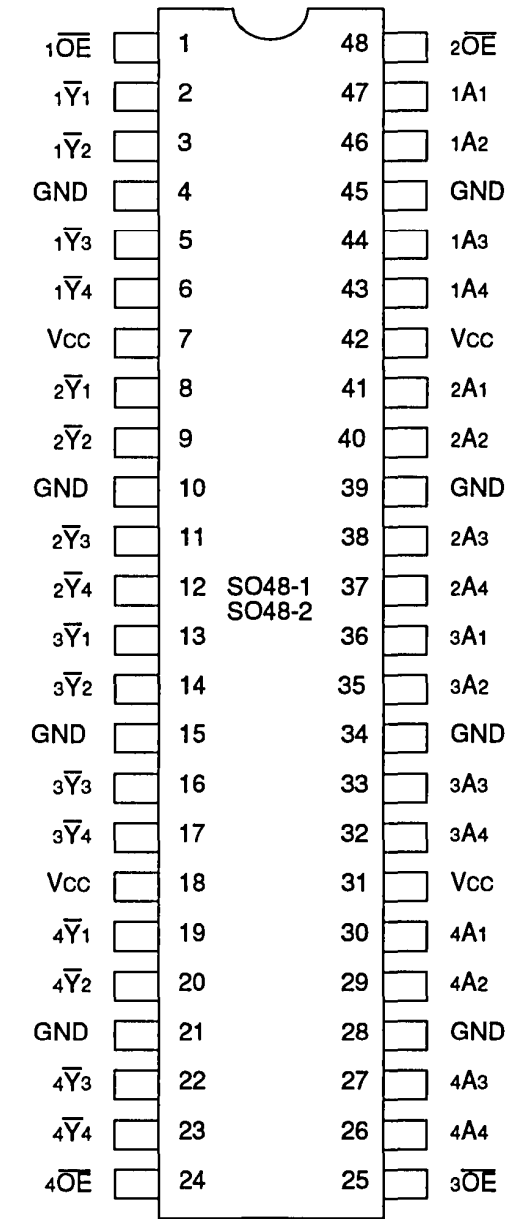
2541 drw 02

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MILITARY AND COMMERCIAL TEMPERATURE RANGES

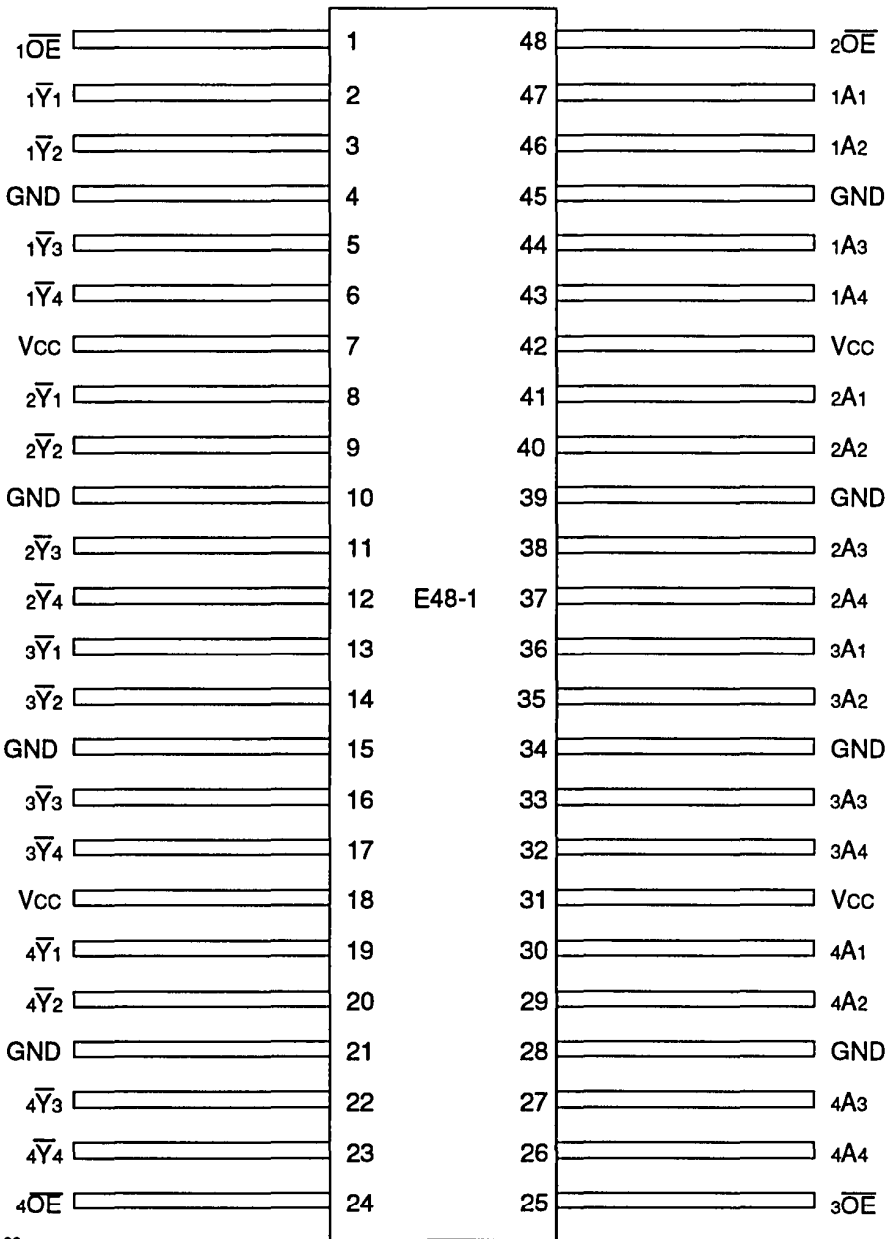
AUGUST 1993

PIN CONFIGURATIONS



SSOP
TSSOP
TOP VIEW

2541 drw 03



CERPACK
TOP VIEW

2541drw 04

PIN DESCRIPTION

Pin Names	Description
$\overline{xOE}$	3-State Output Enable Inputs (Active LOW)
xAx	Data Inputs
xYx	3-State Outputs

2541 tbl 01

FUNCTION TABLE⁽¹⁾

Inputs		Outputs
$\overline{xOE}$	xAx	xYx
L	L	H
L	H	L
H	X	Z

NOTE:

1. H = HIGH Voltage Level
X = Don't Care
L = LOW Voltage Level
Z = High Impedance

2541 tbl 02

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Commercial	Military	Unit
$V_{TERM}^{(2)}$	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	V
$V_{TERM}^{(3)}$	Terminal Voltage with Respect to GND	-0.5 to V_{CC}	-0.5 to V_{CC}	V
T_A	Operating Temperature	-40 to +85	-55 to +125	°C
T_{BIAS}	Temperature Under Bias	-55 to +125	-65 to +135	°C
T_{STG}	Storage Temperature	-55 to +125	-65 to +150	°C
P_T	Power Dissipation	1.0	1.0	W
I_{OUT}	DC Output Current	-60 to +120	-60 to +120	mA

NOTES:

2541 lmk 03

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. All device terminals except FCT162XXXT Output and I/O terminals.
3. Output and I/O terminals for FCT162XXXT.

CAPACITANCE ($T_A = +25^\circ\text{C}$, $f = 1.0\text{MHz}$)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	$V_{IN} = 0V$	4.5	6.0	pF
C_{OUT}	Output Capacitance	$V_{OUT} = 0V$	5.5	8.0	pF

NOTE:

1. This parameter is measured at characterization but not tested.

2541 lmk 04

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Commercial: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 5.0\text{V} \pm 10\%$; Military: $T_A = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, $V_{CC} = 5.0\text{V} \pm 10\%$

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
V_{IH}	Input HIGH Level	Guaranteed Logic HIGH Level		2.0	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I_{IH}	Input HIGH Current (Input pins) ⁽⁵⁾	$V_{CC} = \text{Max.}$	$V_i = V_{CC}$	—	—	± 1	μA
	Input HIGH Current (I/O pins) ⁽⁵⁾			—	—	± 1	
I_{IL}	Input LOW Current (Input pins) ⁽⁵⁾		$V_i = \text{GND}$	—	—	± 1	
	Input LOW Current (I/O pins) ⁽⁵⁾			—	—	± 1	
I_{OZH}	High Impedance Output Current (3-State Output pins) ⁽⁵⁾	$V_{CC} = \text{Max.}$	$V_o = 2.7\text{V}$	—	—	± 1	μA
I_{OZL}			$V_o = 0.5\text{V}$	—	—	± 1	
V_{IK}	Clamp Diode Voltage	$V_{CC} = \text{Min.}$, $I_{IN} = -18\text{mA}$		—	-0.7	-1.2	V
I_{OS}	Short Circuit Current	$V_{CC} = \text{Max.}$, $V_o = \text{GND}^{(3)}$		-80	-140	-200	mA
I_O	Output Drive Current	$V_{CC} = \text{Max.}$, $V_o = 2.5\text{V}^{(3)}$		-50	—	-180	mA
V_H	Input Hysteresis	—		—	100	—	mV
I_{CCL} I_{CCH} I_{CCZ}	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$, $V_{IN} = \text{GND}$ or V_{CC}		—	5	500	μA

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OUTPUT DRIVE CHARACTERISTICS FOR FCT16240T

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -3\text{mA}$	2.5	3.5	—	V
			$I_{OH} = -12\text{mA MIL.}$	2.4	3.5	—	V
			$I_{OH} = -15\text{mA COM'L.}$	—	—	—	—
			$I_{OH} = -24\text{mA MIL.}$	2.0	3.0	—	V
			$I_{OH} = -32\text{mA COM'L.}^{(4)}$	—	—	—	—
V_{OL}	Output LOW Voltage	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 48\text{mA MIL.}$ $I_{OL} = 64\text{mA COM'L.}$	—	0.2	0.55	V
I_{OFF}	Input/Output Power Off Leakage ⁽⁵⁾	$V_{CC} = 0\text{V}$, V_{IN} or $V_o \leq 4.5\text{V}$		—	—	± 1	μA

2541 Ink 06

OUTPUT DRIVE CHARACTERISTICS FOR FCT162240T

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
I_{ODL}	Output LOW Current	$V_{CC} = 5\text{V}$, $V_{IN} = V_{IH}$ or V_{IL} , $V_{OUT} = 1.5\text{V}^{(3)}$		60	115	150	mA
I_{ODH}	Output HIGH Current	$V_{CC} = 5\text{V}$, $V_{IN} = V_{IH}$ or V_{IL} , $V_{OUT} = 1.5\text{V}^{(3)}$		-60	-115	-150	mA
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -16\text{mA MIL.}$ $I_{OH} = -24\text{mA COM'L.}$	2.4	3.3	—	V
V_{OL}	Output LOW Voltage	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 16\text{mA MIL.}$ $I_{OL} = 24\text{mA COM'L.}$	—	0.3	0.55	V

2541 Ink 07

NOTES:

- For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at $V_{CC} = 5.0\text{V}$, $+25^{\circ}\text{C}$ ambient.
- Not more than one output should be tested at one time. Duration of the test should not exceed one second.
- Duration of the condition can not exceed one second.
- The test limit for this parameter is $\pm 5\mu\text{A}$ at $T_A = -55^{\circ}\text{C}$.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$ $V_{IN} = 3.4V^{(3)}$		—	0.5	1.5	mA
I_{CCD}	Dynamic Power Supply Current ⁽⁴⁾	$V_{CC} = \text{Max.}$ Outputs Open $\overline{xOE} = \text{GND}$ One Input Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	—	60	100	$\mu A /$ MHz
I_C	Total Power Supply Current ⁽⁶⁾	$V_{CC} = \text{Max.}$ Outputs Open $f_i = 10\text{MHz}$ 50% Duty Cycle $\overline{xOE} = \text{GND}$ One Bit Toggling	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	—	0.6	1.5	mA
			$V_{IN} = 3.4V$ $V_{IN} = \text{GND}$	—	0.9	2.3	
		$V_{CC} = \text{Max.}$ Outputs Open $f_i = 2.5\text{MHz}$ 50% Duty Cycle $\overline{xOE} = \text{GND}$ Sixteen Bits Toggling	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	—	2.4	4.5 ⁽⁵⁾	
			$V_{IN} = 3.4V$ $V_{IN} = \text{GND}$	—	6.4	16.5 ⁽⁵⁾	

NOTES:

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1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at $V_{CC} = 5.0V$, $+25^{\circ}C$ ambient.

3. Per TTL driven input ($V_{IN} = 3.4V$). All other inputs at V_{CC} or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP} N_{CP} / 2 + f_i N_i)$
 $I_{CC} = \text{Quiescent Current (} I_{CCL}, I_{CCH} \text{ and } I_{CCZ} \text{)}$
 $\Delta I_{CC} = \text{Power Supply Current for a TTL High Input (} V_{IN} = 3.4V \text{)}$
 $D_H = \text{Duty Cycle for TTL Inputs High}$
 $N_T = \text{Number of TTL Inputs at } D_H$
 $I_{CCD} = \text{Dynamic Current Caused by an Input Transition Pair (HLH or LHL)}$
 $f_{CP} = \text{Clock Frequency for Register Devices (Zero for Non-Register Devices)}$
 $N_{CP} = \text{Number of Clock Inputs at } f_{CP}$
 $f_i = \text{Input Frequency}$
 $N_i = \text{Number of Inputs at } f_i$

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Condition ⁽¹⁾	FCT16240T/162240T				FCT16240AT/162240AT				Unit
			Com'l.		Mil.		Com'l.		Mil.		
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	
tPLH tPHL	Propagation Delay xAx to xYx	CL = 50pF RL = 500Ω	1.5	8.0	1.5	9.0	1.5	4.8	1.5	5.1	ns
tPZH tPZL	Output Enable Time		1.5	10.0	1.5	10.5	1.5	6.2	1.5	6.5	ns
tPHZ tPLZ	Output Disable Time		1.5	9.5	1.5	10.0	1.5	5.6	1.5	5.9	ns
tsk(o)	Output Skew ⁽³⁾		—	0.5	—	0.5	—	0.5	—	0.5	ns

Symbol	Parameter	Condition ⁽¹⁾	FCT16240CT/162240CT				FCT16240ET/162240ET				Unit
			Com'l.		Mil.		Com'l.		Mil.		
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	
tPLH tPHL	Propagation Delay xAX to xYx	CL = 50pF RL = 500Ω	1.5	4.3	1.5	4.7	1.5	3.2	—	—	ns
tPZH tPZL	Output Enable Time		1.5	5.8	1.5	6.5	1.5	4.4	—	—	ns
tPHZ tPLZ	Output Disable Time		1.5	5.2	1.5	5.7	1.5	3.6	—	—	ns
tsk(o)	Output Skew ⁽³⁾		—	0.5	—	0.5	—	0.5	—	—	ns

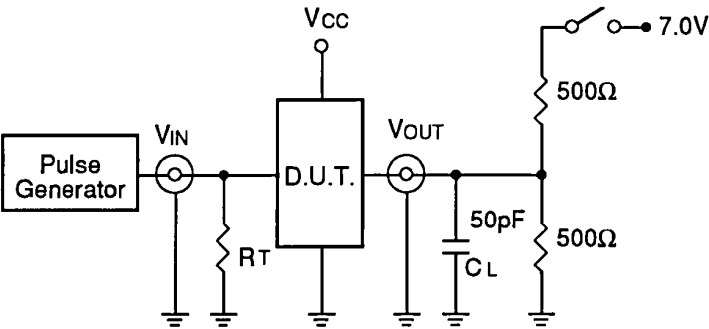
NOTES:

1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

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TEST CIRCUITS AND WAVEFORMS

TEST CIRCUITS FOR ALL OUTPUTS



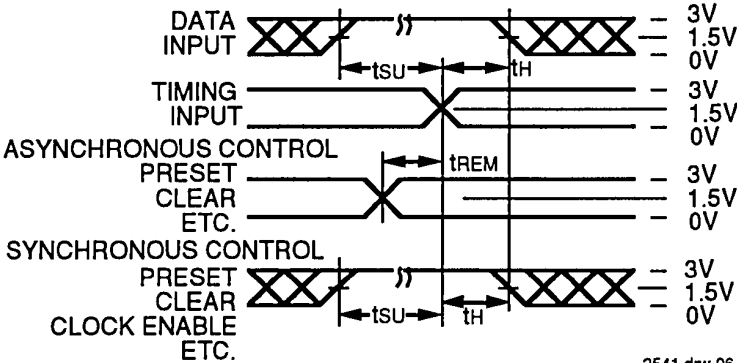
2541 drw 05

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

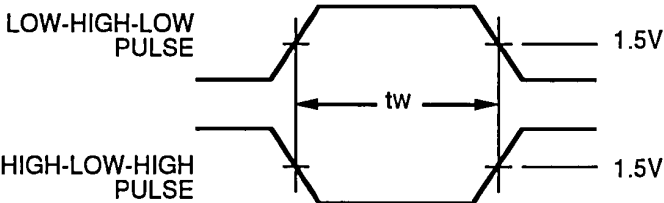
DEFINITIONS: 2541 Ink 10
CL= Load capacitance; includes jig and probe capacitance.
RT= Termination resistance; should be equal to ZOUT of the Pulse Generator.

SET-UP, HOLD AND RELEASE TIMES



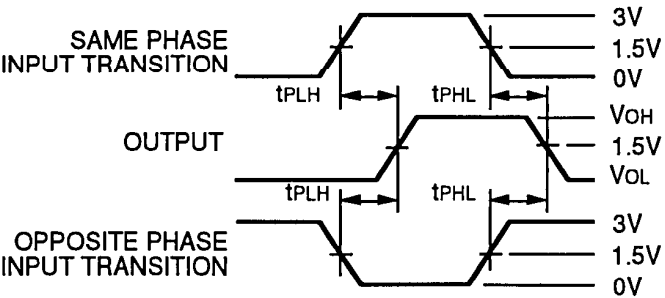
2541 drw 06

PULSE WIDTH



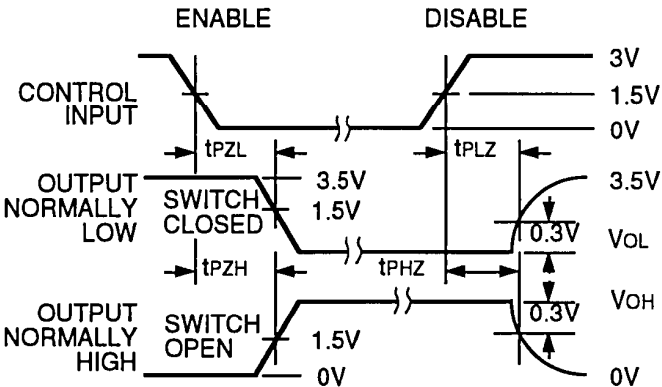
2541 drw 07

PROPAGATION DELAY



2541 drw 08

ENABLE AND DISABLE TIMES



2541 drw 09

- NOTES:
- Diagram shown for input Control Enable-LOW and input Control Disable-HIGH
 - Pulse Generator for All Pulses: Rate ≤ 1.0 MHz; tr ≤ 2.5ns; tr ≤ 2.5ns

ORDERING INFORMATION

IDT	XX	FCT	XXXX	X	X	
Temp. Range		Device Type		Package	Process	
					Blank B	Commercial MIL-STD-883, Class B
					PV PA E	Shrink Small Outline Package (SO48-1) Thin Shrink Small Outline Package (SO48-1) CERPACK (E48-1)
					16240T 16240AT 16240CT 16240ET 162240T 162240AT 162240CT 162240ET	Inverting 16-Bit Buffer/Line Driver
				54 74		−55°C to +125°C −40°C to +85°C

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